TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MZ244FK

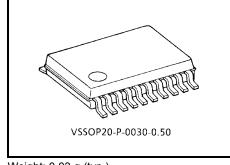
Low Voltage Octal Bus Buffer with 5 V Tolerant Inputs and Outputs

The TC7MZ244FK is a high performance CMOS octal bus buffer. Designed for use in 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) $V_{\rm CC}$ applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The TC7MZ244FK is a non-inverting 3-state buffer having two active-low output enables. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.



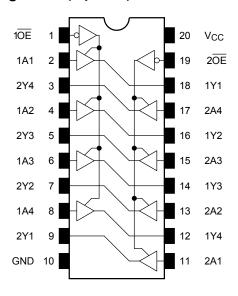
Weight: 0.03 g (typ.)

Features

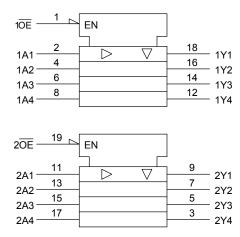
- Low voltage operation: $V_{CC} = 2.0 \sim 3.6 \text{ V}$
- High speed operation: $t_{pd} = 6.5 \text{ ns (max)} (V_{CC} = 3.0 \sim 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Latch-up performance: -500 mA
- Package: VSSOP (US20)
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 244 type.

1 2007-10-19

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inp	uts	Outputs
ŌE	An	Outputs
L	L	L
L	Н	Н
Н	Х	Z

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vout	−0.5~7.0 (Note 2)	V
DC output voltage	VOUT	-0.5~V _{CC} + 0.5 (Note 3)	V
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	−65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0~3.6	
Supply voltage	vcc vcc	1.5~3.6 (Note 2)	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	Vout	0~5.5 (Note 3)	V
Output voltage	VOU1	0~V _{CC} (Note 4)	V
Output current	Ioh/Iol	±24 (Note 5)	mA
Output current	iOH/iOL	±12 (Note 6)	ШК
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in off-state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \sim 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics ($Ta = -40 \sim 85$ °C)

Charact	Characteristics Symbol Test Condition				Min	May	Llmit	
Characte	EUSUCS	Syllibol			V _{CC} (V)	Min	Max	Unit
Input voltage	High level	V_{IH}		_	2.7~3.6	2.0	_	V
iliput voitage	Low level	V _{IL}		_	2.7~3.6	1	0.8	٧
			$I_{OH} = -100 \mu A$	2.7~3.6	V _{CC} - 0.2			
	High level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	
I and board	V	V V 27V	I _{OL} = 100 μA	2.7~3.6	_	0.2		
			$I_{OL} = 12 \text{ mA}$	2.7	_	0.4		
	Low level	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 16 \text{ mA}$	3.0	_	0.4	
			$I_{OL} = 24 \text{ mA}$	3.0	_	0.55		
Input leakage cu	ırrent	I _{IN}	V _{IN} = 0~5.5 V		2.7~3.6	_	±5.0	μΑ
3-state output off-state current		1	$V_{IN} = V_{IH}$ or V_{IL}		2.7~3.6		±5.0	^
		loz	V _{OUT} = 0~5.5 V		2.1~3.0	_	±3.0	μΑ
Power off leakag	ge current	l _{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0		10.0	μΑ
Quiescent supply current		1	$V_{IN} = V_{CC}$ or GND		2.7~3.6	_	10.0	
Quiescent suppi	Quiescent supply current I _{CC}		V _{IN} /V _{OUT} = 3.6~5.5 V		2.7~3.6	_	±10.0	μΑ
Increase in I _{CC}	per input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6	_	500	



AC Characteristics ($Ta = -40 \sim 85$ °C)

Characteristics	Symbol Test Condition			Min	Max	Unit
Characteristics			V _{CC} (V)	IVIIII		
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7		7.5	- ns
Tropagation delay time	t_{pHL}	rigate 1, rigate 2	3.3 ± 0.3	1.5	6.5	
Output enable time	t_{pZL}	Figure 1, Figure 3	2.7		9.0	- ns
	t _{pZH}		3.3 ± 0.3	1.5	8.0	
Output disable time	t_{pLZ}	Figure 1, Figure 3	2.7		8.0	ns
	t _{pHZ}		3.3 ± 0.3	1.5	7.0	110
Output to output skew	t _{osLH}	(Note)	2.7			ns
	t _{osHL}	(Note)	3.3 ± 0.3	_	1.0	115

Note: This parameter is guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, Input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	8.0	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (Typ.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$	ote) 3.3	25	pF

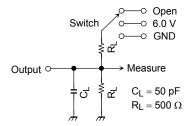
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

AC Test Circuit

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Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

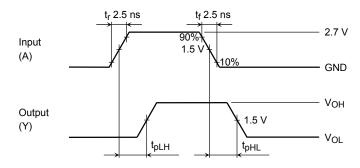


Figure 2 t_{pLH}, t_{pHL}

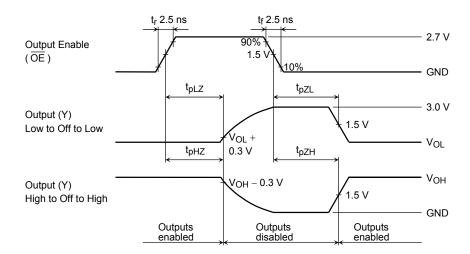
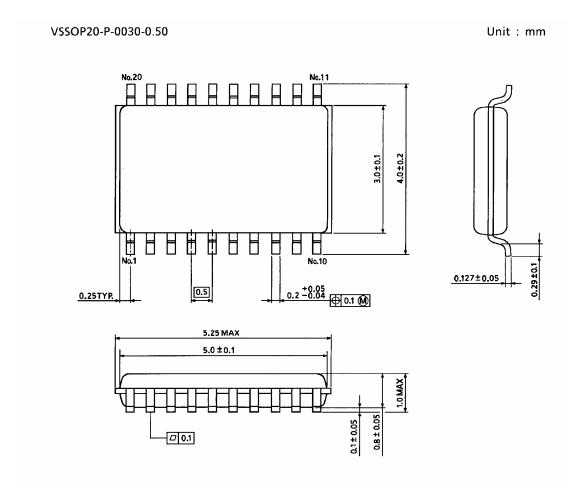


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Package Dimensions



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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